

Technical Data Sheet

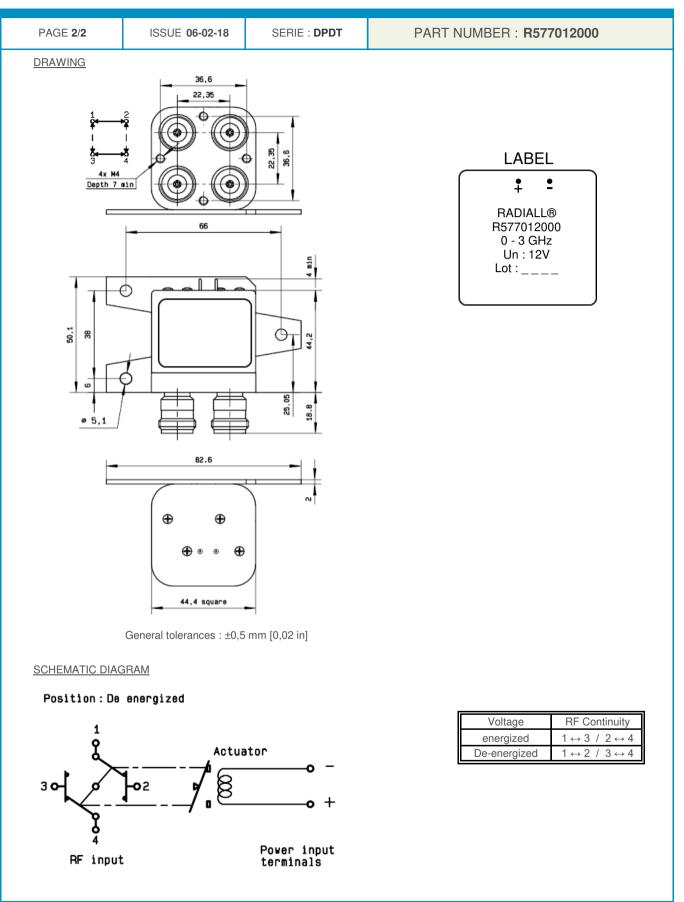
DPDT Ramses N 3GHz Failsafe 12Vdc Pins Terminals with bracket

<u>RF C</u>	HARACTERIS	<u>STICS</u>						
	Frequency ra	ange			: 0 - 3 GHz : 50 Ohms			
Frequency (GHz) VSWR max Insertion loss max Isolation min Average power (*)		DC - 1 1.15 0.15 dB 85 dB 700 W	1 - 2 1.20 0.20 dB 80 dB 500 W	2 - 3 1.25 0.25 dB 75 dB 400 W				
<u>ELE(</u>	Actuator Nominal curr Actuator volt Terminals	rent **	<u>rics</u>		: FAILSAFE : 340 mA : 12V (10.2 to : solder pins	13V) (250°C max. / 30 sec	.)	
MECHANICAL CHARACTERISTICS Connectors Life Switching Time*** Construction Weight				 N female per MIL-C 39012 2.5 million cycles < 15 ms Splashproof < 215 g 				
<u>ENV</u>	IRONMENTAL	_ CHARACTI	ERISTICS					
Operating temperature range Storage temperature range				∷ -40°C to +85 ∷ -55°C to +85		Rot	3	
(* (** (***	Average pov At 25° C ±10 Nominal volt)%)	er RF Path)				· COMPL	IAN IAN



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